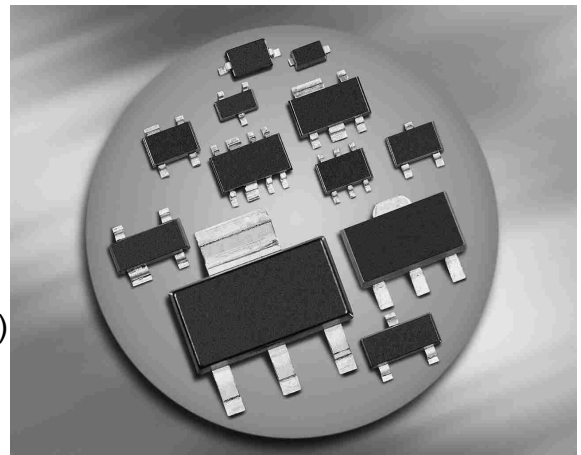
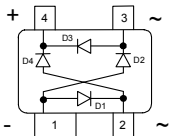


Low VF Schottky Diode Array

- Reverse voltage: 40 V
- Forward current: 0.2 A
- Small diode quad array for polarity independence, reverse polarity protection and low loss bridge rectification
- Very low forward voltage: 0.55 @ 0.1 A (per diode)
- Fast switching
- Pb-free (ROHS compliant) package
- Qualified according AEC Q101



BAS4002A-RPP



Type	Package	Configuration	Marking
BAS4002A-RPP	SOT143	bridge	E9s

Maximum Ratings at $T_A = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage ¹⁾	V_R	40	V
Peak reverse voltage ¹⁾	V_{RM}	40	
RMS reverse voltage ¹⁾	$V_{R(RMS)}$	28	
Forward current ¹⁾ , $T_S \leq 124\text{ °C}$	I_F	200	mA
Non-repetitive peak surge forward current ($t \leq 10\text{ ms}$)	I_{FSM}	2	A
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ²⁾	R_{thJS}	≤ 130	K/W

¹⁾For $T_A > 25\text{ °C}$ the derating of V_R and I_F has to be considered.

²⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

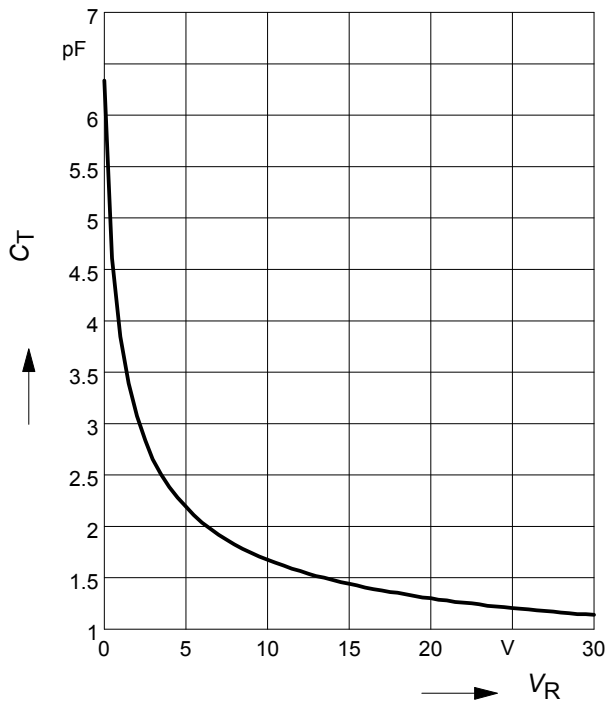
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Reverse current ¹⁾ (per diode) $V_R = 30\text{ V}$ $V_R = 40\text{ V}$	I_R	 - -	 - -	 2 10	μA
Forward voltage ^{1) 2)} (per diode) $I_F = 10\text{ mA}$ $I_F = 60\text{ mA}$ $I_F = 100\text{ mA}$ $I_F = 200\text{ mA}$	V_F	 - - - -	 0.39 0.49 0.55 0.69	 0.44 0.55 0.62 0.79	V
AC Characteristics					
Diode capacitance (per diode) $V_R = 5\text{ V}, f = 1\text{ MHz}$	C_T	 -	 2	 5	pF

¹Pulsed test, $t_p = 300\text{ }\mu\text{s}$; $D = 0.01$

²When used as shown for Reverse Polarity Protection (RPP, see page 4), the voltage available to the circuit being protected will be two diode drops below the power supply voltage. In other words, the supply current will pass through two diodes.

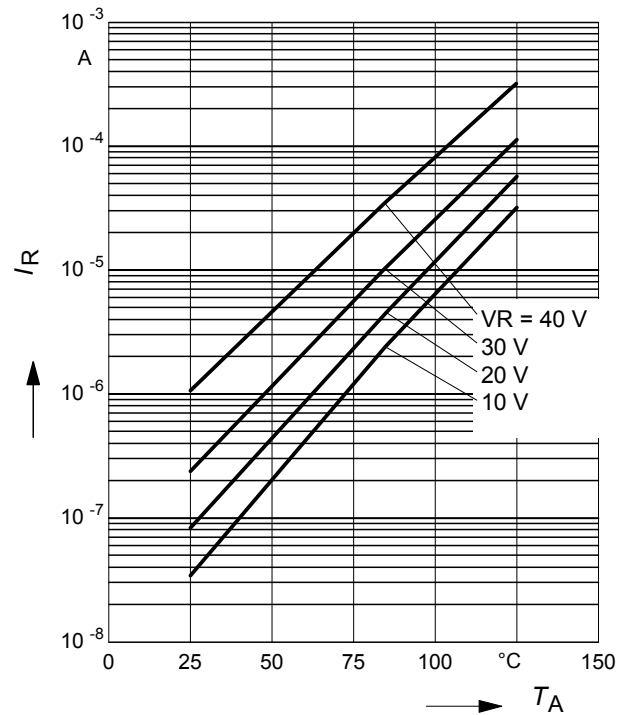
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$ (per diode)



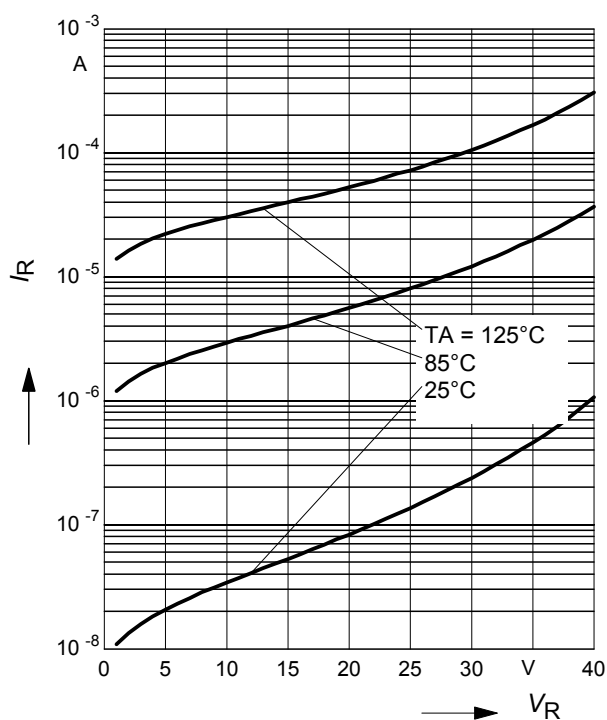
Reverse current $I_R = f(T_A)$

$V_R = \text{Parameter}$ (per diode)



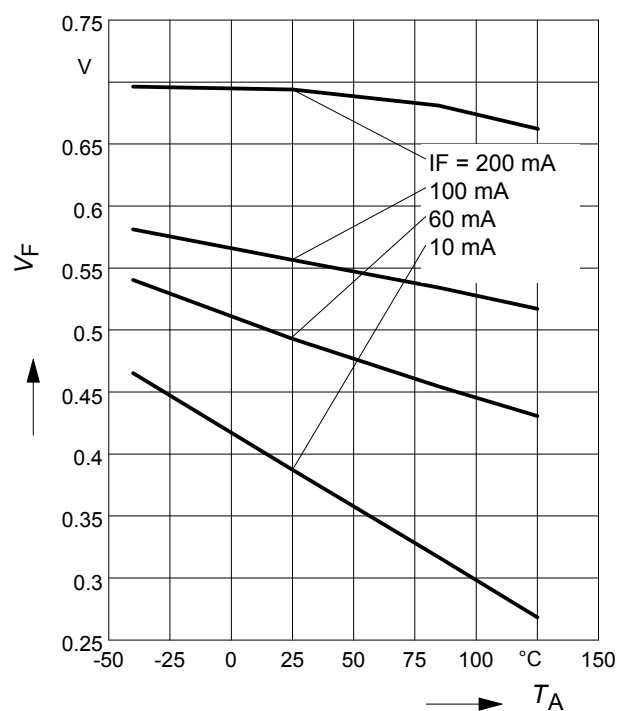
Reverse current $I_R = f(V_R)$

$T_A = \text{Parameter}$ (per diode)

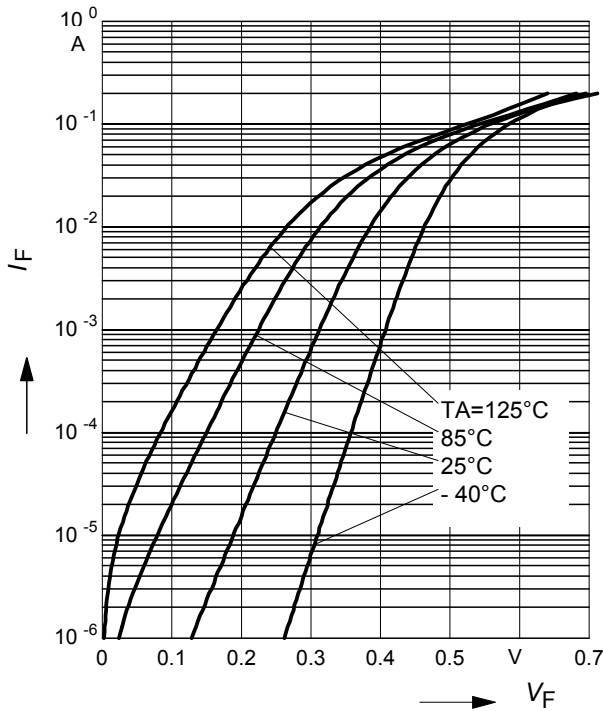


Forward Voltage $V_F = f(T_A)$

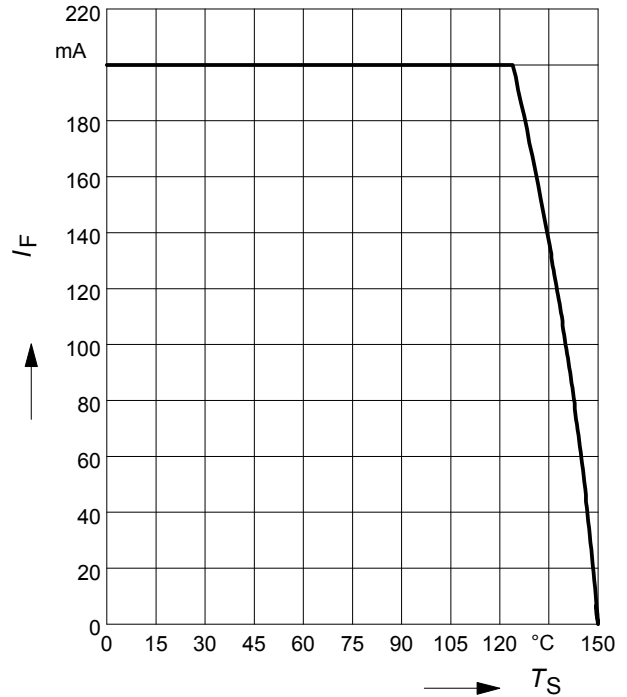
$I_F = \text{Parameter}$ (per diode)



Forward current $I_F = f(V_F)$
(per diode)

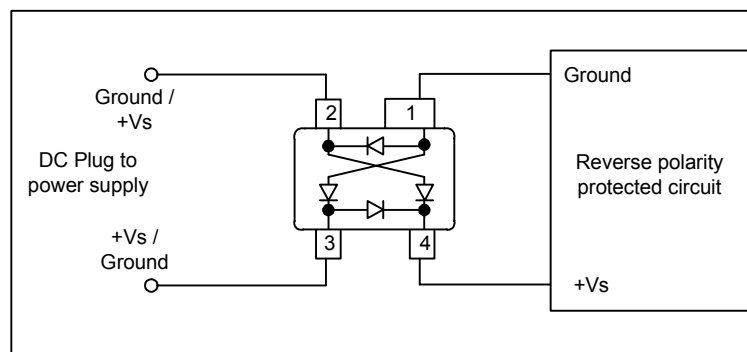


Forward current $I_F = f(T_S)$
BAS4002-RPP



Application example BAS4002A-RPP

Advanced Reverse Polarity Protection(RPP): due to diode orientation, circuit at the right will be protected from damage and will also function normally in the event reverse polarity is applied to pins 2 and 3 of the BAS4002A-RPP.



Technical drawing of a 4-pin connector. The drawing includes a 3D perspective view on the left and two 2D cross-sectional views on the right. The 2D views show the connector's profile with various dimensions and tolerances. Key dimensions include: overall width 2.9 ± 0.1 , pin spacing 1.9 , pin diameter 0.2 , pin length $0.8^{+0.1}_{-0.05}$, pin thickness $0.4^{+0.1}_{-0.05}$, and overall height 1.7 . The 3D view shows the connector's shape and the location of the four pins, labeled 1, 2, 3, and 4. The 2D views also show the connector's profile with dimensions 0.15 MIN. , 1 ± 0.1 , 0.1 MAX. , 2.4 ± 0.15 , 10° MAX. , $0.08 \dots 0.15$, $0 \dots 8^\circ$, and 1.3 ± 0.1 . The drawing is labeled with 'A' and 'B' at the bottom right.

Diagram illustrating the marking on the BFP181 package:

- Manufacturer:** infineon
- Date code (YM):** 2005, June
- Pin 1:** Indicated by the bottom-left pin.
- Type code:** BFP181

Edition 2006-02-01

Published by

Infineon Technologies AG

81726 München, Germany

© Infineon Technologies AG 2007.

All Rights Reserved.

Attention please!

The information given in this dokument shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie"). With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system.

Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.